



isc Silicon NPN Power Transistor

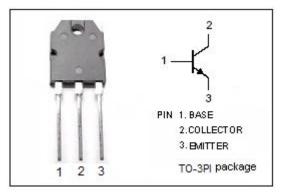
2SC3181

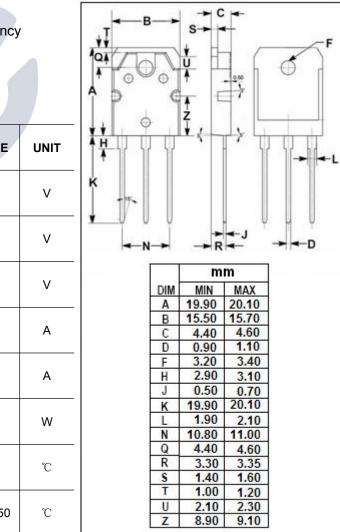
DESCRIPTION

- Low Collector Saturation Voltage-: V_{CE(sat)}= 2.0V(Max.) @I_C= 6A
- · Good Linearity of hFE
- Complement to Type 2SA1264
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Power amplifier applications
- Recommend for 55W high fidelity audio frequency amplifier output stage applications





ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|---|---------|------|
| V _{CBO} | Collector-Base Voltage | 120 | V |
| V _{CEO} | Collector-Emitter Voltage | 120 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| Ic | Collector Current-Continuous | 8 | A |
| I _B | Base Current-Continuous | 0.8 | A |
| Pc | Collector Power Dissipation @ T_C =25°C | 80 | W |
| TJ | Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature Range | -55~150 | °C |



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ELECTRICAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | МАХ | UNIT |
|----------------------|--------------------------------------|---|-----|------|-----|------|
| V(BR)CEO | Collector-Emitter Breakdown Voltage | I _C = 50mA; I _B = 0 | 120 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 6A; I _B = 0.6A | | | 2.0 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = 4A; V _{CE} = 5V | | | 1.5 | V |
| Ісво | Collector Cutoff Current | V _{CB} = 120V; I _E = 0 | | | 5 | μA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 5V; I _C = 0 | | | 5 | μA |
| h _{FE-1} | DC Current Gain | I _C = 1A; V _{CE} = 5V | 55 | | 160 | |
| h _{FE-2} | DC Current Gain | I _C = 4A; V _{CE} = 5V | 35 | | | |
| Сов | Output Capacitance | I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz | | 190 | | pF |
| fT | Current-Gain—Bandwidth Product | I _C = 1A; V _{CE} = 5V | | 30 | | MHz |

h_{FE-1} Classifications

| R | ο | |
|--------|--------|--|
| 55-110 | 80-160 | |

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